Form 1449 (Modified) Atty. Docket No. IBM1P009/SJ0920010140US1 Information Disclosure Statement By Applicant Wayne L. Cheung et al. Filing Date: Group Art Unit:

(Use Several Sheets if Necessary)

U.S. Patent Documents

Herewith

Unassigned

Examiner						Sub-	Filing
Initial	No.	Patent No.	Date	Patentee	Class	class	Date
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Initial	No.	No.	Date	Patent Office	Class	class	Yes	No	
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Other Documents

No.	Author, Title, Date, Place (e.g. Journal) of Publication					
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S	Lam, Steve et al; A 550Mb/s GMR Read/Write Amplifier using 0.5µm 5V CMOS Process, 2000 IEEE International, February 7-9, 2000					
T	Gray, Paul R. et al; Analysis and Design of Analog Integrated Circuits third Edition, John Wiley & Sons, Inc.					
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Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.